NSN 5961-00-883-7200

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-883-7200 **Inclosure Material:** Metal **Overall Length:** 0.850 inches **Overall Diameter:** 0.290 inches **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 15.0 reverse voltage, instantaneous **Current Rating Per Characteristic:** 67.00 milliamperes forward current, average peak **Power Rating Per Characteristic:** 1.0 watts small-signal input power, common-collector **Test Data Document:** 81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 2 uninsulated wire lead **Specification Data:** 81349-mil-s-19500/145 government specification Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig:

A110a0

Mil-std (military Standard):

Mil-prf-19500 spec.